

UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address COMMISSIONER FOR PATENTS P.O. Box 1450 print 2011-1450

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/091,193	03/05/2002	Howard Hao Chen	YOR91999-0420-US2	6354
75	90 11/19/2003		EXAM	INER
Anne Vachon Dougherty 3173 Cedar Road			TRAN, TAN N	
Yorktown Heights, NY 10598			ART UNIT	PAPER NUMBER
	,		2826	

DATE MAILED: 11/19/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

•		Application No.	Applicant(s)			
Office Action Summary		10/091,193	CHEN ET AL. 1			
		Examiner	Art Unit			
		TAN N TRAN	2826			
Period fo	The MAILING DATE of this communication ap or Reply	ppears on the cover sheet with the	correspondence address			
THE - Exte after - If the - If NO - Failt - Any	ORTENED STATUTORY PERIOD FOR REPI MAILING DATE OF THIS COMMUNICATION. Inscisor of time may be available under the provisions of 3 CFR 1 SIX (6) MONTHS from the mailing date of this communication. SIX (6) MONTHS from the mailing date of this communication, pained for regly specified above is uses than thing (20) days, a reg- pand for regly specified above is uses than thing (20) days, a reg- vire to regly within the set or extended period for regly will, by state regly received by the Office later than three months after the maili of patent term adjustment. See 37 CFR 1,704(b).	. 136(a). In no event, however, may a reply be to ply within the statutory minimum of thirty (30) da at will apply and will expire SIX (6) MONTHS to. cause the application to become ABANDONS	mely filed ys will be considered timely, the mailing date of this communication. ED (35 U.S. C. § 133).			
1) 🖂	Responsive to communication(s) filed on res	sponse filed on 09/18/03 .				
2a)☐	This action is FINAL. 2b)⊠ T	his action is non-final.				
3)∐ Disposit	Since this application is in condition for allow closed in accordance with the practice unde ion of Claims	vance except for formal matters, p r Ex parte Quayle, 1935 C.D. 11,	rosecution as to the merits is 453 O.G. 213.			
4)⊠	Claim(s) 1-20 is/are pending in the application	on.				
	4a) Of the above claim(s) 15-20 is/are withdra	awn from consideration.				
5)[5) Claim(s) is/are allowed.					
6)⊠	6)⊠ Claim(s) <u>1-14</u> is/are rejected.					
7)	7) Claim(s) is/are objected to.					
	Claim(s) are subject to restriction and/ ion Papers	or election requirement.				
9)☐ The specification is objected to by the Examiner.						
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.						
If approved, corrected drawings are required in reply to this Office action.						
12)	The oath or declaration is objected to by the E	xaminer.				
Priority ι	under 35 U.S.C. §§ 119 and 120					
13)	Acknowledgment is made of a claim for foreig	gn priority under 35 U.S.C. § 119(a	a)-(d) or (f).			
a)	☐ All b)☐ Some * c)☐ None of:					
	1. Certified copies of the priority document	nts have been received.				
	2. Certified copies of the priority document	nts have been received in Applicat	ion No			
* 5	 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). See the attached detailed Office action for a list of the certified copies not received. 					
	Acknowledgment is made of a claim for domes					
а) ☐ The translation of the foreign language pr Acknowledgment is made of a claim for domes	rovisional application has been red	ceived.			
Attachmen		. ,				
2) Notic	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informal	y (PTO-413) Paper No(s) Patent Application (PTO-152)			

Application/Control Number: 10/091,193

Art Unit: 2826

DETAILED ACTION

Information Disclosure Statement

 If applicant is aware of any relevant prior art, he/she requested to cite it on form PTO-1449 in accordance with the guidelines set forth in M.P.E.P.

609.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1,3,4-6,8-13 are rejected under 35 U.S.C. 102(b) as being anticipated by Chiang et al. (5,739,579).

With regard to claim 1, Chiang et al. discloses a substrate 20; two adjacent conductors 61, disposed in at least one dielectric layer 50 formed over the substrate 20 and electrically isolated from each other, wherein each pair of adjacent conductors 61 is separated by a gap, and a first material 50 made of silicon dioxide and formed in the gap between two adjacent conductors 61. (Note fig. 9 of Chiang et al.). It is inherent that silicon dioxide is a high dielectric constant material in order to increase the capacitance between the conductors. Note lines 9,10, paragraph 0007, page 1 of Liou et al. (2002/0008301) are cited to support for the inherent position.

With regard to claims 2,8, Chiang et al. discloses at least one successive conductor level comprising at least one conductor 94 is provided over the adjacent conductors 61, further comprising second material 91 made of silicon dioxide functions as a second high dielectric constant material and disposed between one of the adjacent conductors 61 and the at least one successive conductor level having conductor 94. (Note fig. 9 of Chiang et al.).

With regard to claim 4, Chiang et al. discloses the conductors are fabricated from at least one of group consisting of Au, Cu. (Note lines 52-54, column 6 of Chiang et al.).

With regard to claims 5,6, Chiang et al. discloses a TiN diffusion barrier 60 formed between the high dielectric constant material 50 and the conductors 61. (Note fig. 9 of Chiang et al.).

With regard to claim 9, Chiang et al. discloses the at least one successive conductor level comprises a first successive level comprising at least one conductive via 94 electrically coupled to conductor 61. (Note fig. 9 of Chiang et al.).

With regard to claim 10, Chiang et al. discloses the at least one successive conductor level additionally comprises a second successive level comprising additional adjacent conductors 97 disposed above the first successive level. (Note fig. 9 of Chiang et al.).

With regard to claim 11, Chiang et al. discloses the second conductor level additionally comprises third material made of silicon dioxide functions as a high dielectric constant material disposed between the additional adjacent conductors 97. (Note fig. 9 of Chiang et al.).

With regard to claim 12, Chiang et al. discloses at least one electrically conductive barrier material 93 disposed between the second high dielectric constant material 91 and the at least one conductor 61. (Note fig. 9 of Chiang et al.).

Application/Control Number: 10/091,193

Art Unit: 2826

With regard to claim 13, Chiang et al. discloses at least one electrically conductive barrier material 96 disposed between the third high dielectric constant 95 and the additional adjacent conductors 97. (Note fig. 9 of Chiang et al.).

Claims 1,3 are rejected under 35 U.S.C. 102(b) as being anticipated by Summerfelt (5,909,043).

With regard to claims 1,3, Summerfelt discloses a substrate 40; two adjacent conductors 42, disposed in at least one dielectric layer 54 formed over the substrate 40 and electrically isolated from each other, wherein each pair of adjacent conductors 42 is separated by a gap, and a first material 46 made of barium strontium titanate having high dielectric constant and formed in the gap between two adjacent conductors 42. (Note lines 40-42, column 1, fig. 13 of Summerfelt).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all
obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 7,14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Chiang et al. (5,739,579).

With regard to claim 7, Chiang et al. does not disclose at least one pair of adjacent conductors comprises a power supply lines and a ground lines. However, it would have been obvious to one of ordinary skill in the art to form at least one pair of adjacent conductors comprises a power supply lines and a ground lines in order to activate the device. Note lines 24-37, column 4 of Lee (5,903,493) are cited to support for the well know position.

With regard to claim 14, Chiang et al. discloses all the claimed subject matter except for the gap is in the range 0.1 to 2.0 microns. However, it would have been obvious to one of ordinary skill in the art to form the gap is in the range 0.1 to 2.0 microns in order to minimize the size of the device.

Conclusion

4. Any inquiry concerning this communication or earlier communication from the examiner should be directed to Tan Tran whose telephone number is (703) 305-3362. The examiner can normally be reached on M-F 8:30AM-5PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn can be reached on (703) 308-6601. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 872-9318 for regular communications and (703) 872-9319 for after final communications.

Application/Control Number: 10/091,193

Art Unit: 2826

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

TT

Oct 2003

Minhloan Tran
Primary Examine
Art Unit 2826